

A "Clean" copy of the claims amended herein.

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1. (Twice Amended) A reflection type liquid crystal display, comprising:
a pair of substrates disposed opposite to each other with a liquid crystal layer
disposed therebetween;
a plurality of switching elements formed on one surface of at least one of said pair
of substrates;
a reflective layer constituted of a same material as an electrode of said plurality of
switching elements and simultaneously formed during formation of said electrode of said
plurality of switching elements on a same plane as a plane of said electrode; and
a transparent pixel electrode formed on said reflective layer via an insulation layer
and connected to at least one electrode included in at least one of said plurality of
switching elements.

B1

2. (Twice Amended) The reflection type liquid crystal display according to claim
1, wherein said plurality of switching elements includes at least a thin film transistor, and
said reflective layer is formed of the same material as a material of a gate electrode of
said thin film transistor and formed on the same plane as a plane of said gate electrode.

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5. (Twice Amended) The reflection type liquid crystal display according to claim
1, wherein a shielding layer is disposed on an area of at least one of said plurality of
switching elements.

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8. (Twice Amended) The reflection type liquid crystal display according to claim 1, wherein said reflective layer is formed of at least one of aluminum and an aluminum alloy.

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12. (Once Amended) The reflection type liquid crystal display according to claim 1, wherein at least one rough portion is formed below said reflective layer, and said reflective layer is formed to cover said at least one rough portion.

B5
25. (Once Amended) A reflection type liquid crystal display, comprising:
a pair of substrates disposed opposite to each other via a liquid crystal layer;
a plurality of switching elements formed on one surface of said pair of substrates;
a reflective layer constituted of a same material as a material constituting said switching element and simultaneously formed during formation of said switching elements;

a transparent pixel electrode formed on said reflective layer via an insulation layer and connected to one electrode constituting said switching element;

wherein said switching element is a thin film transistor, and said reflective layer is formed of the same material as a material of a gate electrode of said thin film transistor and constituted on the same plane as a plane of said gate electrode; and

wherein a rough portion is formed below said reflective layer, and said reflective layer is formed to cover said rough portion.

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26. (Once Amended) A reflection type liquid crystal display, comprising:
a pair of substrates disposed opposite to each other via a liquid crystal layer;
a plurality of switching elements formed on one surface of said pair of substrates;
a reflective layer constituted of a same material as a material constituting said
switching element and simultaneously formed during formation of said switching
elements;

a transparent pixel electrode formed on said reflective layer via an insulation layer
and connected to one electrode constituting said switching element;

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wherein said thin film transistor comprises a gate electrode electrically connected
to a scanning line, a gate insulation film formed to cover said gate electrode, a
semiconductor layer formed on said gate insulation film, a drain electrode electrically
connected to a signal line, and a source electrode electrically connected to said
transparent pixel electrode, and said reflective layer is electrically separated from said
gate electrode; and

wherein a rough portion is formed below said reflective layer, and said reflective
layer is formed to cover said rough portion.